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Key indicators

Single-crystal X-ray study T = 194 K Mean σ (C—C) = 0.006 Å Disorder in solvent or counterion R factor = 0.035 wR factor = 0.104 Data-to-parameter ratio = 13.6

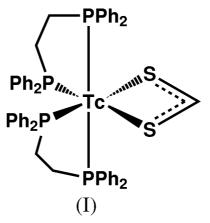
For details of how these key indicators were automatically derived from the article, see http://journals.iucr.org/e. Two Tc-containing products were isolated from the reaction between CS₂ and the electron-deficient complex TcCl(dppe)₂. The title dithioformate complex, $[Tc(S_2CH)(dppe)_2] \cdot 3C_6H_6$, where dppe is 1,2-bis(diphenylphosphino)ethane (C₂₆H₂₄P₂), exhibits Tc-P bond lengths ranging from 2.3566 (14) to 2.3884 (14) Å, which are little shorter than normally found. The other product is $[TcCl(CS)(dppe)_2]$, and is the first reported Tc-thiocarbonyl complex.

Bis[1,2-bis(diphenylphosphino)ethane-P,P']-

(dithioformato-S,S')technetium tris(benzene) solvate

Comment

The title compound, (I), was prepared during an examination of the reactivity of the 16-electron complex [TcCl(dppe)₂], where dppe is 1,2-bis(diphenylphosphino)ethane (Burrell *et al.*, 1994). It is the first structural characterization of the dithioformate ligand on Tc. Only one other Tc-dithioformate complex, $[Tc(S_2CH)(CO)_2(PPh_3)_2]$ has been previously reported, but its structure was not determined (Cook *et al.*, 1995).



The structure of the title compound (Fig. 1) is quite similar to isoelectronic, and isostructural $[Fe(S_2CH)(depe)_2]^+$ (Bianchini *et al.*, 1982), and the closely related technetium(II) complexes $[Tc(S_2CNMe_2)(depe)_2]^+$ (Okamoto *et al.*, 1993) and $[Tc(S_2CNMe_2)(dppe)_2]^+$ (Rochon *et al.*, 1992). The Tc-P bond lengths range from 2.3566 (14) to 2.3884 (14) Å, which are little shorter than normally observed. A search of the Cambridge Structural Database (Allen & Kennard, 1993) indicates that most Tc-P bonds range from 2.39 to 2.50 Å, with a mean value of 2.44 Å.

Experimental

 $[TcCl(dppe)_2]$ (100 mg) was added to a benzene (50 ml) solution containing CS₂ (0.2 ml) and triphenylphosphine (50 mg). This mixture was heated to reflux for 2 min and then allowed to cool. Hexane was added to the solution and then the mixture was allowed Received 10 October 2000 Accepted 16 November 2000 Online 1 December 2000

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metal-organic papers

to stand. Over time, a mixture of orange and yellow crystals were deposited. The orange crystals proved to be $[Tc(S_2CH)(dppe)_2]$ - $3C_6H_6$ ($C_{71}H_{67}P_4S_2Tc$).

Crystal data

$$\begin{split} & [\text{Tc}(\text{CHS}_2)(\text{C}_{26}\text{H}_{24}\text{P}_2)_2]\cdot 3\text{C}_6\text{H}_6 \\ & M_r = 1207.2 \\ & \text{Triclinic, } P\bar{1} \\ & a = 14.132 \ (4) \text{ Å} \\ & b = 14.738 \ (6) \text{ Å} \\ & c = 17.031 \ (4) \text{ Å} \\ & \alpha = 65.79 \ (3)^\circ \\ & \beta = 88.10 \ (3)^\circ \\ & \gamma = 67.88 \ (3)^\circ \\ & \gamma = 2966 \ (2) \text{ Å}^3 \end{split}$$

Data collection

Nonius CAD-4 diffractometer ω scans Absorption correction: ψ scan (*SHELXTL-Plus*; Siemens, 1990) $T_{min} = 0.854$, $T_{max} = 0.934$ 10 893 measured reflections 10431 independent reflections 7752 reflections with $I > 2\sigma(I)$

Refinement

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Refinement on F^2

R(F) = 0.035

wR(F^2) = 0.104

S = 1.04

10431 reflections

768 parameters

H atoms treated by a mixture of

independent and constrained

refinement
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Z = 2 $D_x = 1.35 \text{ Mg m}^{-3}$ Mo K α radiation Cell parameters from 25 reflections $\theta = 7.6-11.9^{\circ}$ $\mu = 0.46 \text{ mm}^{-1}$ T = 193 K Block, red–orange $0.35 \times 0.23 \times 0.15 \text{ mm}$

 $R_{int} = 0.029$ $\theta_{max} = 25.0^{\circ}$ $h = 0 \rightarrow 16$ $k = -16 \rightarrow 17$ $l = -20 \rightarrow 20$ 3 standard reflections frequency: 120 min intensity decay: 8%

$$\begin{split} &w = 1/[\sigma^2(F_o^2) + (0.0493P)^2 \\ &+ 0.5423P] \\ &where \ P = (F_o^2 + 2F_c^2)/3 \\ (\Delta/\sigma)_{\rm max} = 0.008 \\ \Delta\rho_{\rm max} = 0.56 \ {\rm e} \ {\rm \AA}^{-3} \\ \Delta\rho_{\rm min} = -0.43 \ {\rm e} \ {\rm \AA}^{-3} \end{split}$$

Two of the benzene solvate molecules are disordered and each is modeled over two sites (68:32 and 73:27). The 1,1- and 1,3-distances, as well as the U_{ij} components of bonded or closely spaced disordered atoms are restrained to be similar. Despite the restraints, three atoms exhibit unusual elongation, and two of these (C118 and C120) are refined isotropically. All other non-H atoms are refined anisotropically. The dithioformate H atom (H5) was located in a difference map, and its coordinates were allowed to refine, with $U_{iso}(H)$ equal to $1.5U_{iso}(C5)$. All other H atoms were placed in calculated positions, refined using a riding model, and given an isotropic displacement parameter equal to 1.2 times the equivalent isotropic displacement parameter of the atom to which they were attached.

Data collection: CAD-4 Software (Enraf–Nonius, 1989); cell refinement: CAD-4 Software; data reduction: XCAD4 (Harms, 1993);

e 1

Selected geo	metric paramete	ers (A, °).
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Tc-S1	2.4866 (14)	Tc-P2	2.3632 (14)
Tc-S2	2.4548 (15)	Tc-P3	2.3566 (14)
Tc-P1	2.3650 (14)	Tc-P4	2.3884 (14)
S1–Tc–S2	68.38 (4)	S2–Tc–P4	85.93 (5)
S1-Tc-P1	89.52 (4)	P1-Tc-P2	82.05 (4)
S1-Tc-P2	160.79 (5)	P1-Tc-P3	94.05 (4)
S1-Tc-P3	103.41 (5)	P1-Tc-P4	175.03 (5)
S1-Tc-P4	89.41 (4)	P2-Tc-P3	94.42 (5)
S2-Tc-P1	98.18 (5)	P2-Tc-P4	100.39 (4)
S2-Tc-P2	95.66 (5)	P3-Tc-P4	81.48 (4)
S2-Tc-P3	165.10 (5)	S1-C5-S2	112.5 (3)

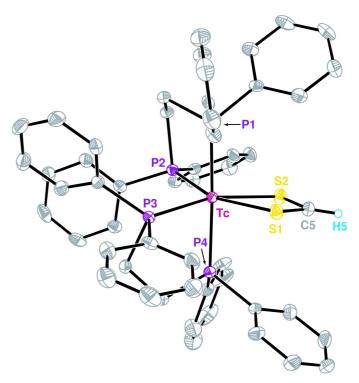


Figure 1

The molecular structure of the title compound showing 50% probability displacement ellipsoids. The benzene solvate molecules, and all H atoms, except H5 have been omitted for clarity.

program(s) used to solve structure: *SHELXS86* (Sheldrick, 1985); program(s) used to refine structure: *SHELXL97* (Sheldrick, 1997); molecular graphics: *SHELXTL* (Bruker, 1997); software used to prepare material for publication: *PLATON* (Spek, 2000).

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References

- Allen, F. H. & Kennard, O. (1993). Chem. Des. Autom. News, 8, 1, 31-37.
- Bianchini, C., Innocenti, P., Meli, A., Orlandini, A. & Scapacci, G. (1982). J. Organomet. Chem. 233, 233.
- Bruker (1997). SHELXTL. Version 5.10/IRIX. Bruker AXS Inc., Madison, Wisconsin, USA.
- Burrell, A. K., Kubas, G. J. & Bryan, J. C. (1994). J. Am. Chem. Soc. 116, 1575– 1576.
- Cook, J., Davison, A., Davis, W. M. & Jones, A. G. (1995). Organometallics, 14, 650–655.
- Enraf-Nonius (1989). *CAD-4 Software*. Version 5.0. Enraf-Nonius, Delft, The Netherlands.
- Harms, K. (1993). XCAD4. University of Marburg, Germany.
- Okamoto, K., Chen, B., Kirchhoff, J. R., Ho, D. M., Heineman, W. R., Deutsch, E. & Heeg, M. J. (1993). *Polyhedron*, **12**, 1559.
- Rochon, F. D., Melanson, R. & Kong, P.-C. (1992). Inorg. Chim. Acta, 194, 43– 50.

Sheldrick, G. M. (1985). SHELXS86. Crystallographic Computing 3, edited by G. M. Sheldrick, C. Krüger & R. Goddard, pp. 175–189. Oxford University Press.

Sheldrick, G. M. (1997). SHELXL97. University of Göttingen, Germany.

Siemens (1990). SHELXTL-Plus. Version 4.21. Siemens Analytical X-ray Instruments Inc., Madison, Wisconsin, USA.

Spek, A. L. (2000). PLATON. Utrecht University, The Netherlands.